



MAPRST0912-350 Information

www.helsener.com

For Reference Only

Part Number MAPRST0912-350

Manufacturer M/A-Com Technology Solutions
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF

Description TRANS NPN 350W 960MHZ-1215MHZ

Package -

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MAPRST0912-350 Specifications

Manufacturer Part Number	MAPRST0912-350
Manufacturer	M/A-Com Technology Solutions
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	-
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	65V
Frequency - Transition	1.215GHz
Noise Figure (dB Typ @ f)	-
Gain	9.4dB
Power - Max	350W
DC Current Gain (hFE) (Min) @ Ic, Vce	-
Current - Collector (Ic) (Max)	32.5A
Operating Temperature	200°C (TJ)
Mounting Type	Chassis Mount
Package / Case	-
Supplier Device Package	-
	Report errors?

MAPRST0912-350 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MAPRST0912-350 Payment Methods



















MAPRST0912-350 Shipping Methods













If you have any question about MAPRST0912-350, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com